## NSN 5961-01-334-0997



Unitized Semiconductor Devices - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-334-0997 **Inclosure Material:** Metal **Overall Length:** Between 1.490 inches and 1.510 inches **Overall Height:** 0.650 inches **Overall Width:** Between 1.490 inches and 1.510 inches **Function For Which Designed:** Transient suppressor **End Application:** 5865-01-188-3309 jammer system respo an/ulq-1 (v) 1 **Component Name And Quantity:** 6 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 28.0 regulator voltage all semiconductor device diode **Current Rating Per Characteristic:** 50.00 microamperes forward current, average peak all semiconductor device diode **Power Rating Per Characteristic:** 350.0 watts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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